-	Hits	Search Text	DB	Time stamp
L Number	HILS			
1	102		USPAT;	2002/08/09
	0.1	recess)	US-PGPUB USPAT;	14:40 2002/08/09
2	81	((438/455).CCLS.) and (void or cavity)	US-PGPUB	12:06
3	21	(((438/455).CCLS.) and (void or cavity or	USPAT;	2002/08/09
		recess)) not (((438/455).CCLS.) and (void	US-PGPUB	12:44
		or cavity))		2002/02/02
4	10		USPAT; US-PGPUB	2002/08/09
5	3349	layer) optical adj cavit\$3	USPAT;	2002/08/09
	3349	optical adj cavitys	US-PGPUB	13:07
6	852	(optical adj cavit\$3) and electrode	USPAT;	2002/08/09
			US-PGPUB	12:52
8	167	, ·	USPAT; US-PGPUB	2002/08/09
9	14	(gallium adj arsenide)) same wafer (silicon and (crystalline adj sapphire)	USPAT;	2002/08/09
	14	and ceramic) same substrate	US-PGPUB	12:57
10	9	((silicon and (silicon adj carbide) and	USPAT;	2002/08/09
		(gallium adj arsenide)) same wafer) and	US-PGPUB	12:57
	F 2 2	mems	USPAT;	2002/08/09
7	538	((optical adj cavit\$3) and electrode) and mirror	US-PGPUB	13:05
13	1	(optical adj cavit\$3) and ((silicon and	USPAT;	2002/08/09
		(silicon adj carbide) and (gallium adj	US-PGPUB	13:11
		arsenide) and sapphire and ceramic) same		
1.6	4	<pre>(wafer or substrate)) (optical adj cavit\$3) and ((silicon and</pre>	USPAT;	2002/08/09
16	3	(silicon adj carbide) and (gallium adj	US-PGPUB	13:17
		arsenide)) same (wafer or substrate))		
17	603	recess near2 bevel\$2	USPAT;	2002/08/09
1.0	4.1	minnen mass? /giligon adi /dioxide or	US-PGPUB USPAT;	14:03 2002/08/09
18	41	mirror near2 (silicon adj (dioxide or oxide))	US-PGPUB	13:19
23	7	optical and mirror and ((recess or void	USPAT;	2002/08/09
		or cavity) near2 bevel\$2)	US-PGPUB	14:39
25	13	((438/455).CCLS.) and bevel\$2	USPAT; US-PGPUB	2002/08/09
	1572	mems	USPAT	2002/07/28
1	1572			15:30
-	170	mems and bridge	USPAT	2002/07/28
			IICDAM.	16:52
-	897	(bridge\$1 same (void or space or cavity or hole or recess)) and (438/\$.ccls. or	USPAT; US-PGPUB	2002/07/28
		257/\$.ccls.)	05 10101	
-	42	mems and bridge\$1 and (438/\$.ccls. or	USPAT;	2002/07/28
		257/\$.ccls.)	US-PGPUB	16:55
-	330	mems and bridge\$1	USPAT; US-PGPUB	2002/08/05
_	400	substrate near2 bond\$2 near2 wafer	USPAT;	2002/08/02
1	400		US-PGPUB	14:29
-	1	(US-20020045297-\$).did.	US-PGPUB	2002/08/02
	224	/floate2 on morrable) and ME	USPAT;	13:22
-	824	(float\$3 or movable) and MEms	US-PGPUB	14:37
_	667	((float\$3 or movable) and MEms) and	USPAT;	2002/08/02
		(bridge or member or element)	US-PGPUB	14:39
-	10		USPAT;	2002/08/07
		(bridge or member or element)) and (substrate near2 bond\$3 near2 wafer)	US-PGPUB	15:36
_	394		USPAT;	2002/08/05
			US-PGPUB	14:50
-	1	(US-20020086456-\$).did.	US-PGPUB	2002/08/05
	70.00	wariable adi? canadites	USPAT;	14:18
_	7263	variable adj3 capacitor	US-PGPUB	14:51
_	187	accelerometer and mems	USPAT;	2002/08/05
			US-PGPUB	14:51
_	5765	variable adj2 capacitor	USPAT; US-PGPUB	2002/08/05
	<u> </u>		US FGFUB	1 + 1 · V +

Search History 8/9/02 2:43:53 PM

			<u>-</u>	
-	5050	variable adj capacitor	USPAT;	2002/08/05
	:		US-PGPUB	14:51
_	76	(variable adj capacitor) and mems	USPAT;	2002/08/05
		•	US-PGPUB	14:52
_	1	(US-6405592-\$).did.	USPAT	2002/08/05
				23:47
-	1	(US-6344417-\$).did.	USPAT	2002/08/05
				23:53
_	1	(US-6408878-\$).did.	USPAT	2002/08/06
				11:38
_	456	(438/455).CCLS.	USPAT;	2002/08/06
			US-PGPUB	13:29
_	1	(US-6356689-\$).did.	USPAT	2002/08/06
	_	,		14:29
_	1	(US-5656512-\$).did.	USPAT	2002/08/06
	_			16:06
_	259	(438/52).CCLS.	USPAT;	2002/08/07
		(100,01,011)	US-PGPUB	14:04
_	275	(216/17).CCLS.	USPAT;	2002/08/07
		(220, 21, 7000201	US-PGPUB	13:04
_	9	((216/17).CCLS.) and (mems or	USPAT;	2002/08/07
		microelectric)	US-PGPUB	13:05
	51	l ·	USPAT;	2002/08/07
		microelectric)	US-PGPUB	13:12
_	251		USPAT;	2002/08/07
	231	(130) 100) 100201	US-PGPUB	14:25
<u>_</u>	35	((438/406).CCLS.) and (cavity or void)	USPAT;	2002/08/07
	ĺ	((150) 100) 100251, and (00120) 01 1014,	US-PGPUB	14:11
<u>_</u>	71	(438/379).CCLS.	USPAT;	2002/08/07
_	/ -	(430/3/3/100231	US-PGPUB	14:25
_	128	(438/456).CCLS.	USPAT;	2002/08/07
	120	(430) 130) .0020.	US-PGPUB	14:42
l _	57	((438/456).CCLS.) and (cavity or void)	USPAT;	2002/08/07
)	((130) 100) 10020 1) and (00120)	US-PGPUB	14:49
<u>_</u>	14	mems and accelerometer and bridge and	USPAT;	2002/08/07
	**	(void or cavity)	US-PGPUB	15:04
_	54		USPAT;	2002/08/07
		(substrate same wafer)	US-PGPUB	15:04
_	345		USPAT;	2002/08/07
		(cavity or void)	US-PGPUB	15:45
_	8558	T	USPAT;	2002/08/07
			US-PGPUB	17:03
_	105	accelerometer and (cavity or void) and	USPAT;	2002/08/07
		(substrate near5 wafer)	US-PGPUB	15:54
_	1616	1 `	USPAT;	2002/08/07
	1		US-PGPUB	17:04
1_	194	(accelerometer\$1 and semiconductor\$1) and	USPAT;	2002/08/09
		(sacrificial\$1 adj layer\$1)	US-PGPUB	10:05
_	4			2002/08/09
		1303151 1322700 0110100 0010050 /.		10:04
1_	2	("3241374" "5719333").PN.	USPAT	2002/08/09
		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		10:04
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